

Powerex General Purpose Rectifier Diodes are designed with high locking voltage capability and low forward voltage drop to minimize conduction losses. These are packaged in hermetic, ceramic Pow-R-Disc packages which can be mounted using commercially available clamps and heatsinks or fully assembled to a variety of air or water cooled heat exchangers.

FEATURES:

- Low On-State Voltage
- Hermetic Ceramic Package
- Excellent Surge and I^2t Ratings

APPLICATIONS:

- DC Power Supplies

ORDERING INFORMATION

Select the complete 12 digit Part Number using the table below.
EXAMPLE: R9G02221XXOO is a 2200V-2100A General Purpose Diode with a typical reverse recovery time of 25 μ s.

PART	Voltage Rating V_{DRM} - V_{RRM}	Voltage Code	Current Rating I_{tavg}	Current Code	Reverse Recovery t_{RR}	Lead Code
R9G0	2200V	22	2100A	21	XX	OO
	2000V	20				
	1800V	18			25 μ s typical	

Absolute Maximum Ratings

Characteristic	Symbol	Rating	Units
Repetitive Peak Reverse Voltage	V_{RRM}	2200	Volts
Average On-State Current, $T_C=118\text{ }^\circ\text{C}$	$I_{F(Avg.)}$	2100	A
RMS On-State Current, $T_C=118\text{ }^\circ\text{C}$	$I_{F(RMS)}$	3299	A
Average On-State Current, $T_C=84\text{ }^\circ\text{C}$	$I_{F(Avg.)}$	3000	A
RMS On-State Current, $T_C=84\text{ }^\circ\text{C}$	$I_{F(RMS)}$	4712	A
Peak One Cycle Surge Current [†] , 60Hz, $V_R=V_{RRM}$	I_{FSM}	22,000	A
Fuse Coordination I^2t , 60Hz	I^2t	2.02E+06	A ² s
Peak One Cycle Surge Current [†] , 60Hz, $V_R=0V$	I_{FSM}	28,600	A
Fuse Coordination I^2t , 50Hz	I^2t	3.41E+06	A ² s
Peak 3 Cycle Surge Current, 60Hz, $V_R=0V$	I_{FSM}	25,080	A
Peak 10 Cycle Surge Current, 60Hz, $V_R=0V$	I_{FSM}	20,130	A
Operating Temperature	T_j	-40 to+175	°C
Storage Temperature	$T_{Stg.}$	-50 to+200	°C
Approximate Weight		1.0	lb
		0.45	Kg
Mounting Force		5500-6000	lbs
		24.5 - 26.7	Knewtons

[†] Per NEMA Std. RS-282

Electrical Characteristics, T_j=25°C unless otherwise specified

Characteristic	Symbol	Test Conditions	Rating			Units
			min	typ	max	
Repetitive Peak Reverse Leakage Current	I _{RRM}	T _j =175°C, V _{RRM} =Rated			75	ma
Peak On-State Voltage	V _{FM}	T _j =25°C, I _{FM} =4000A			1.24	V
V _{FM} Model, Low Level	V ₀	T _j =175°C			0.912	V
V _{FM} = V ₀ + r•I _{FM}	r	15% I _{FM} - π•I _{FM}			8.85E-05	Ω
V _{FM} Model, High Level	V ₀	T _j =175°C			1.059	V
V _{FM} = V ₀ + r•I _{FM}	r	π•I _{FM} - I _{FSM}			6.32E-05	Ω
V _{FM} Model, 4-Term	A	T _j =175°C			0.652	
V _{FM} = A + B•Ln(I _{FM}) +	B	15% I _{FM} - I _{FSM}			0.0381	
C•(I _{FM}) + D•(I _{FM}) ^{1/2}	C				5.730E-05	
	D				0.00111	
Reverse Recovery Time	t _{RR}	T _j =25°C, I _{FM} =1500A di _R /dt = 25 A/μs		25		μs

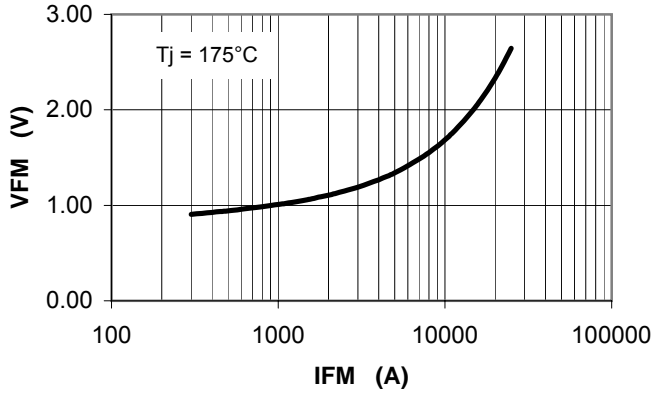
Thermal Characteristics

Characteristic	Symbol	Test Conditions	Rating			Units
			min	typ	max	
Thermal Resistance						
Junction to Case	R _{Θ_{jc}}	Double side cooled		0.018	0.02	°C/Watt
Case to Sink	R _{Θ_{cs}}	Double side cooled		0.004	0.006	°C/Watt

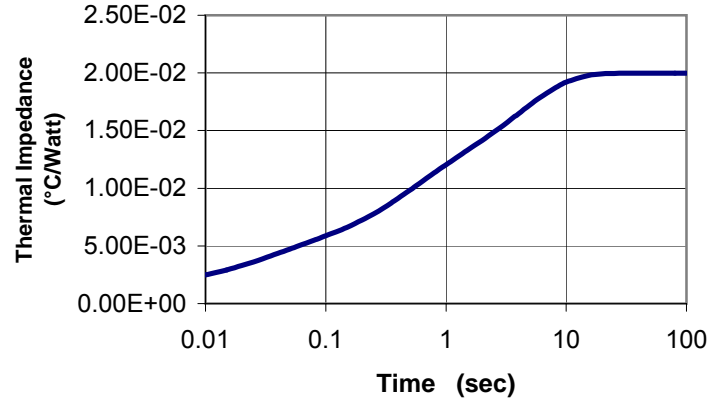
Thermal Impedance Model Z_{Θ_{jc}}(t) = Σ(A(N)•(1-exp(-t/Tau(N)))) where:

N =	1	2	3	4
A(N) =	1.418E-03	2.968E-03	6.066E-03	9.527E-03
Tau(N) =	5.947E-05	2.762E-02	4.011E-01	4.012E+00

Maximum On-State Voltage Drop

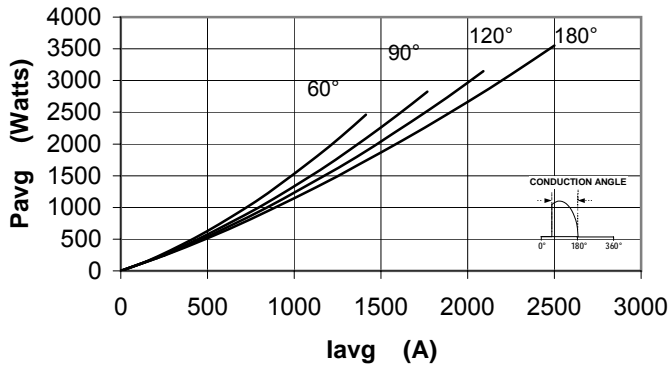


MAXIMUM TRANSIENT THERMAL IMPEDANCE



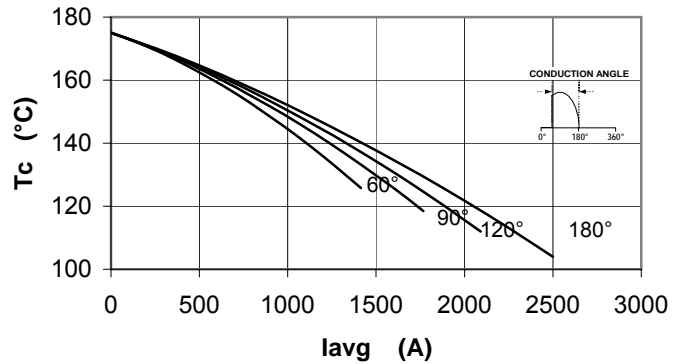
Maximum On-State Power Dissipation

Sinusoidal Waveform



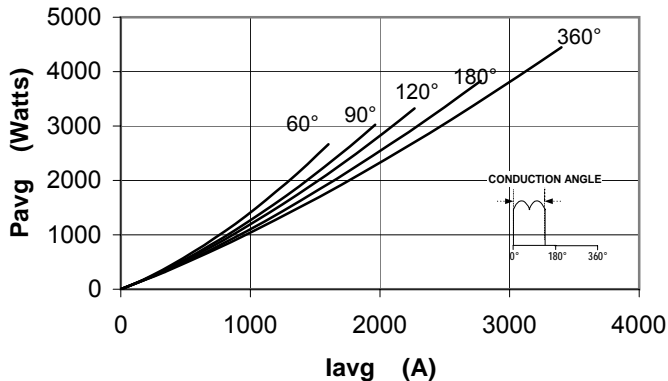
Maximum Allowable Case Temperature

Sinusoidal Waveform



Maximum On-State Power Dissipation

Square Waveform



Maximum Allowable Case Temperature

Square Waveform

